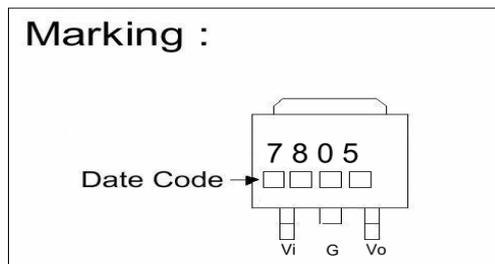
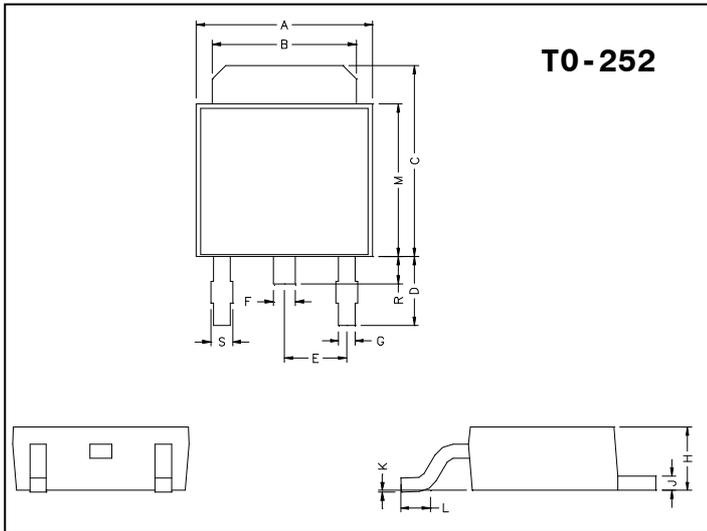


GJ7805

Description

The GJ7805 series of three-terminal positive regulators are available in the TO-252 package and with several fixed output voltages, making it useful in a wide range of applications. These regulators can provide local on-card regulation, eliminating the distribution problems associated with single point regulation. Each type employs internal current limiting, thermal shut-down and safe operating area protection, making it essentially indestructible. If adequate heat sinking is provided, they can deliver can be used with external components to obtain adjustable voltages and currents. GJ7805 is characterized for operation from 0°C to +125°C, and if operating temperature will always high, please refer the power dissipation curve.

Package Dimensions



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	6.40	6.80	G	0.50	0.70
B	5.20	5.50	H	2.20	2.40
C	6.80	7.20	J	0.45	0.55
D	2.20	2.80	K	0	0.15
E	2.30 REF.		L	0.90	1.50
F	0.70	0.90	M	5.40	5.80
S	0.60	0.90	R	0.80	1.20

Absolute Maximum Ratings

Parameter	Ratings	Unit
Input Voltage	35V	V
Operating Junction Temperature Range	0 ~ +150	°C
Output Current	1	A
Storage Temperature Range	-65 ~ +150	°C
Total Power Dissipation	Internal limit	W

Electrical Characteristics

(Refer to the test circuits, Tj=0 to 125°C, Io=500mA, Vi=10V, Ci=0.33uF, Co=0.1uF unless otherwise specified)

Symbol	Rank A (3%)			Unit	Test Conditions
	Min.	Typ.	Max.		
VO	4.85	5	5.15	V	Tj=25°C
	4.85	5	5.15		PD<7W, 5mA ≤ Io ≤ 1A, 7V ≤ Vin ≤ 20V
ΔVO (Line Regulation)	-	4	50	mV	Tj=25°C, 7V ≤ Vin ≤ 25V
	-	1.6	25		Tj=25°C, 8V ≤ Vin ≤ 12V
ΔVO (Load Regulation)	-	-	100	mV	5mA ≤ Io ≤ 1A
	-	-	50		250mA ≤ Io ≤ 750Ma
IQ	-	5.5	8	mA	Tj=25°C
Δ IQ	-	-	0.5	mA	5mA ≤ Io ≤ 1A
	-	-	1.0		7V ≤ Vin ≤ 25V
Vn	-	100	200	uV	Tj=25°C, 10Hz ≤ f ≤ 100KHz
RR	62	68	-	dB	Tj=25°C, 8V ≤ Vin ≤ 18V, f=120Hz
VD	-	2	-	V	Tj=25°C, Io=1A
Isc	-	250	-	mA	Tj=25°C, Vi=35V
Ipk	1.7	-	-	A	Tj=25°C
ΔVo / ΔTj	-	-0.8	-	mV/°C	Io=5mA

(Refer to the test circuits, $T_j=0$ to 125°C , $I_o=500\text{mA}$, $V_i=10\text{V}$, $C_i=0.33\mu\text{F}$, $C_o=0.1\mu\text{F}$ unless otherwise specified)

Rank B (5%)			Unit	Test Conditions	
Symbol	Min.	Typ.			Max.
VO	4.75	5	5.25	V	$T_j=25^\circ\text{C}$
	4.75	5	5.25		$PD<7\text{W}$, $5\text{mA} \leq I_o \leq 1\text{A}$, $7\text{V} \leq V_{in} \leq 20\text{V}$
ΔVO (Line Regulation)	-	4	100	mV	$T_j=25^\circ\text{C}$, $7\text{V} \leq V_{in} \leq 25\text{V}$
	-	1.6	50		$T_j=25^\circ\text{C}$, $8\text{V} \leq V_{in} \leq 12\text{V}$
ΔVO (Load Regulation)	-	-	100	mV	$5\text{mA} \leq I_o \leq 1\text{A}$
	-	-	50		$250\text{mA} \leq I_o \leq 750\text{mA}$
IQ	-	5.5	8	mA	$T_j=25^\circ\text{C}$
ΔIQ	-	-	0.5	mA	$5\text{mA} \leq I_o \leq 1\text{A}$
	-	-	1.0		$7\text{V} \leq V_{in} \leq 25\text{V}$
Vn	-	100	200	μV	$T_j=25^\circ\text{C}$, $10\text{Hz} \leq f \leq 100\text{KHz}$
RR	62	68	-	dB	$T_j=25^\circ\text{C}$, $8\text{V} \leq V_{in} \leq 18\text{V}$, $f=120\text{Hz}$
VD	-	2.0	-	V	$T_j=25^\circ\text{C}$, $I_o=1\text{A}$
Isc	-	250	-	mA	$T_j=25^\circ\text{C}$, $V_i=35\text{V}$
Ipk	1.7	-	-	A	$T_j=25^\circ\text{C}$
$\Delta V_o / \Delta T_j$	-	-0.8	-	$\text{mV}/^\circ\text{C}$	$I_o=5\text{mA}$

Important Notice:

- All rights are reserved. Reproduction in whole or in part is prohibited without the prior written approval of GTM.
- GTM reserves the right to make changes to its products without notice.
- GTM semiconductor products are not warranted to be suitable for use in life-support Applications, or systems.
- GTM assumes no liability for any consequence of customer product design, infringement of patents, or application assistance.

Head Office And Factory:

- **Taiwan:** No. 17-1 Tatung Rd. Fu Kou Hsin-Chu Industrial Park, Hsin-Chu, Taiwan, R. O. C.
TEL : 886-3-597-7061 FAX : 886-3-597-9220, 597-0785
- **China:** (201203) No.255, Jang-Jiang Tsai-Lueng RD. , Pu-Dung-Hsin District, Shang-Hai City, China
TEL : 86-21-5895-7671 ~ 4 FAX : 86-21-38950165